

New Generation of WICOP

High-Power LED – WICOP2 Z8 Y19 SZ8-Y19-XX-XX (Cool, Neutral, Warm)





















Product Brief

Description

- The WICOP2 series is designed for high flux output applications with high current operation capability.
- Compact footprint(1.81x1.81mm) enables system level cost saving
- It incorporates state of the art SMD design and low thermal resistant material.

 The WICOP2 is ideal light sources for directional lighting applications such as Spot Lights, various outdoor applications, automotive lightings and high performance torches.

Features and Benefits

- Designed for high current operation
- Low Thermal Resistance
- A wide CCT range of 2,600~7,000K
- ANSI compliant Binning
- RoHS compliant
- Phosphor film directly attached to chip surface

Key Applications

- Residential Replacement lamps
- Commercial/Industrial Retail Display
- Outdoor area Flood/Street light, High Bay

Table 1. Product Selection Table

Dort Number		ССТ		CRI
Part Number	Color	Min.	Max.	Min
SZ8-Y19-W0-C7	Cool White	4,700K	7,000K	70
SZ8-Y19-W0-C8	Cool White	4,700K	7,000K	80
SZ8-Y19-W0-C9	Cool White	4,700K	7,000K	90
SZ8-Y19-WN-C7	Neutral White	3,700K	4,700K	70
SZ8-Y19-WN-C8	Neutral White	3,700K	4,700K	80
SZ8-Y19-WN-C9	Neutral White	3,700K	4,700K	90
SZ8-Y19-WW-C7	Warm White	2,600K	3,700K	70
SZ8-Y19-WW-C8	Warm White	2,600K	3,700K	80
SZ8-Y19-WW-C9	Warm White	2,600K	3,700K	90



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Performance Characteristics

Table 2. Electro Optical Characteristics, $I_F = 350 \text{mA}$ (CRI 70)

Part Number	ССТ	[K] ^[1]	Min. L	Min. Luminous Flux ^[2] Φ _V ^[3] [lm]			ıminous ³¹ [lm]@ 8		CRI ^[4] , R _a
	Min.	Max.	Group	Flux [lm] @85°C	Flux [lm] @25°C	700mA	1.0A	1.5A	Min.
			W4	160	175	285	376	510	
SZ8-Y19-W0-C7	4700	7000	W3	152	167	271	357	485	70
S26-119-W0-C7	4700	7000	W2	142	156	254	335	455	70
			W1	133	146	237	313	424	
		00 4700	W4	160	175	285	376	510	
SZ8-Y19-WN-C7	3700		W3	152	167	271	357	485	70
526-119-WIN-C7	3700		W2	142	156	254	335	455	70
			W1	133	146	237	313	424	
			W3	152	167	271	357	485	
670 V40 M/M 67	2600	2700	W2	142	156	254	335	455	70
SZ8-Y19-WW-C7	2600	3700 -	W1	133	146	237	313	424	70
			V3	125	137	223	294	399	

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
 - Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.

Performance Characteristics

Table 2. Electro Optical Characteristics, I_F = 350mA (CRI 80)

	ССТ	[K] ^[1]	Min. L	Min. Luminous Flux ^[2] Φ _V ^[3] [lm]			uminous ^{3]} [lm] @ 8		CRI ^[4] , R _a
Part Number	Min.	Max.	Group	Flux [lm] @85°C	Flux [lm] @25°C	700mA	1.0A	1.5A	Min.
			W3	152	167	271	357	485	
SZ8-Y19-W0-C8	4700	7000	W2	142	156	254	335	455	80
S26-119-WU-C6	4700	7000	W1	133	146	237	313	424	80
			V3	125	137	223	294	399	
		00 4700	W3	152	167	271	357	485	
SZ8-Y19-WN-C8	3700		W2	142	156	254	335	455	80
526-1 19-WIN-C6	3700		W1	133	146	237	313	424	00
			V3	125	137	223	294	399	
			W1	133	146	237	313	424	
SZ8-Y19-WW-C8	2000	2700	V3	125	137	223	294	399	00
	2600	3700 -	V2	116	128	208	274	372	80
			V1	109	120	195	257	349	

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
 - Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.

Performance Characteristics

Table 2. Electro Optical Characteristics, $I_F = 350 \text{mA}$ (CRI 90)

	ССТ	ССТ [К] ^[1]		Min. Luminous Flux ^[2] Φ _v ^[3] [lm]			ıminous ^{3]} [lm] @ 8		CRI ^[4] , R _a
Part Number	Min.	Max.	Group	Flux [lm] @85°C	Flux [lm] @25°C	700mA	1.0A	1.5A	Min.
	·		W1	133	146	237	313	424	
SZ8-Y19-W0-C9	4700	7000	V3	125	137	223	294	399	90
S26-119-W0-C9	4700	7000	V2	116	128	208	274	372	. 90
			V1	109	120	195	257	349	
			W1	133	146	237	313	424	
SZ8-Y19-WN-C9	3700		V3	125	137	223	294	399	90
526-119-WN-C9	3700	4700	V2	116	128	208	274	372	90
			V1	109	120	195	257	349	
			V2	116	128	208	274	372	
SZ8-Y19-WW-C9	2600	2700	V1	109	120	195	257	349	90
	2600	2600 3700 -	U3	102	112	182	240	326	90
			U2	96	106	172	227	308	-

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.

Performance Characteristics

Table 3. Absolute Maximum Ratings

Parameter	Cumbal		Value		Unit
rarameter	Symbol	Min.	Тур.	Max.	Onit
Forward Current [1]	I _F	-	-	1.5 ^[4] 2.0 ^[3]	А
Power Dissipation	P_{D}	-	-	7.8	W
Junction Temperature	T _j	-	-	145	°C
Operating Temperature	T_{opr}	- 40	-	125	۰C
Storage Temperature	T_{stg}	- 40	-	125	۰C
Viewing angle	θ		140		degree
Thermal resistance (J to S) [2]	Rθ _{J-S}	-	3 ^[3] 4.5 ^[4]	-	K/W
ESD Sensitivity(HBM)		Class	2 JESD22-A	114-E	

- (1) At Junction Temperature 85 °C condition.
- (2) $R\theta_{J-S}$ is tested at 700mA.
- (3) Using Metal PCB (Dielectric layer 5W/m·K and Cu pattern of 2oz).
- (4) Using Metal PCB (Normal type).
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.

Fig 1. Color Spectrum

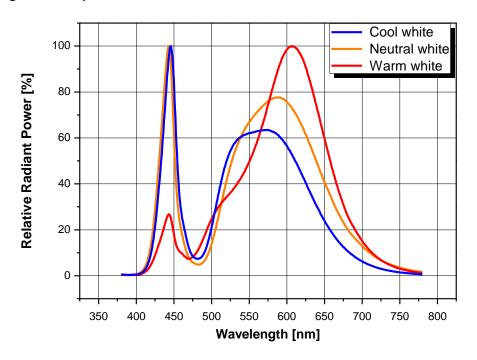


Fig 2. Typical Spatial Distribution

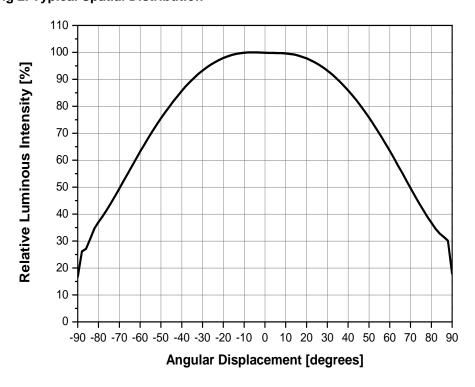


Fig 3. Forward Voltage vs. Forward Current, T_i =85 $^{\circ}$ C

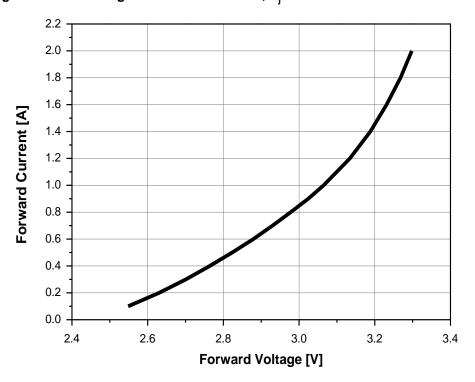


Fig 4. Forward Current vs. Relative Luminous Flux, T_i=85 ℃

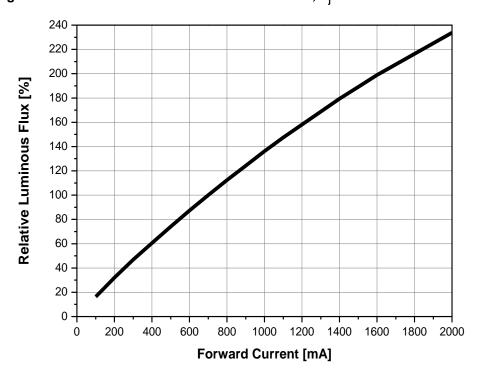


Fig 5. Forward Current vs. CIE X, Y Shift

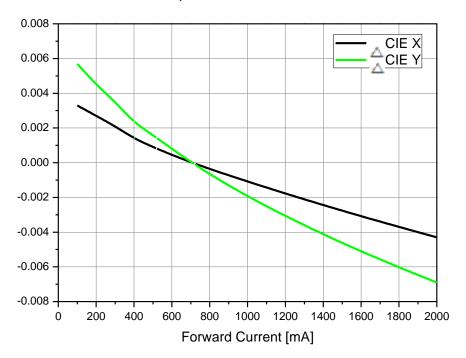


Fig 6. Junction Temp. vs. CIE X, Y Shift

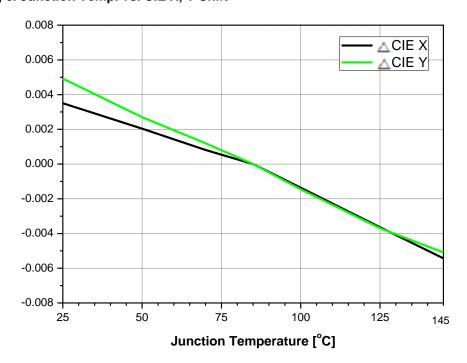


Fig 7. Relative Light Output vs. Junction Temperature, I_F=700mA

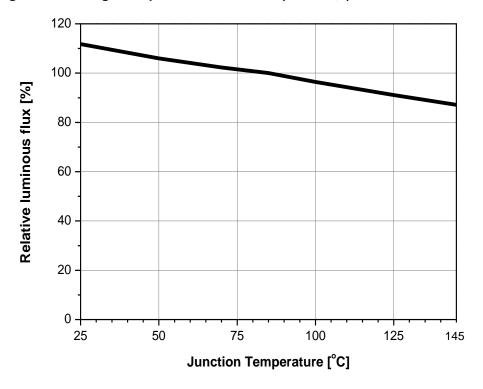


Fig 8. Relative Forward Voltage vs. Junction Temperature, I_F=700mA

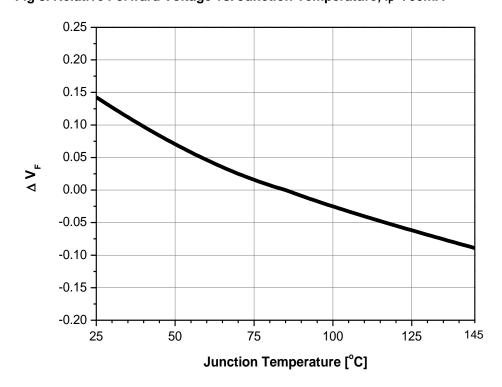
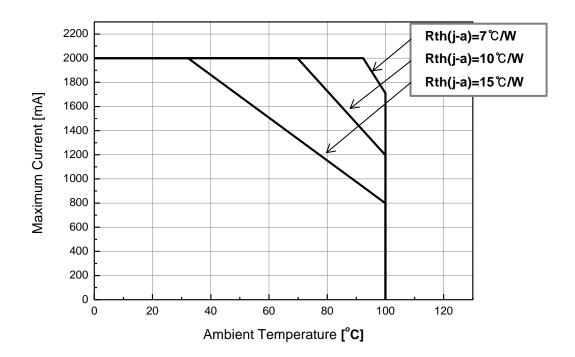


Fig 9. Maximum Forward Current vs. Ambient Temperature, $T_i(max.)=145\,^{\circ}C$, $I_F=2A$



Color Bin Structure

Table 4. Bin Code description, I_F=700mA, T_i=85 ℃ (CRI 70)

Part Number	Luminous Flux [lm]			Color Chromaticity	Typical For	Typical Forward Voltage [V _F] ^{[1]*}			
	Bin Code	Min.	Max.	Coordinate	Bin Code	Min.	Max.		
	W1	237	254	- _ Refer to page 15 -	G	2.75	3.00		
SZ8-Y19-W0-C7	W2	254	271			2.75	3.00		
320-119-00-07	W3	271	285		Н	3.00	3.25		
	W4	285	299		П	3.00	3.25		
	W1	237	254	Refer to page.	G	2.75	3.00		
SZ8-Y19-WN-C7	W2	254	271		G		3.00		
326-1 19-WIN-C/	W3	271	285	16~17		0.00	2.05		
	W4	285	299		Н	3.00	3.25		
	V3	223	237			0.75	2.00		
C70 V40 M/M C7	W1	237	254	Refer to page.	G	2.75	3.00		
SZ8-Y19-WW-C7	W2	254	271	18~20			2.05		
	W3	271	285		Н	3.00	3.25		

Table 5. Luminous Flux rank distribution (CRI 70)

Available Rank

сст	CIE	Luminous Flux Rank								
6,000 ~ 7,000K	Α	V2	V3	W1	W2	W3	W4			
5,300 – 6,000K	В	V2	V3	W1	W2	W3	W4			
4,700 ~ 5,300K	С	V2	V3	W1	W2	W3	W4			
4,200 ~ 4,700K	D	V2	V3	W1	W2	W3	W4			
3,700 ~ 4,200K	E	V2	V3	W1	W2	W3	W4			
3,200 ~ 3,700K	F	V2	V3	W1	W2	W3	W4			
2,900 ~ 3,200K	G	V2	V3	W1	W2	W3	W4			
2,600 ~ 2,900K	Н	V2	V3	W1	W2	W3	W4			

- (1) Tolerance is $\pm 0.06V$ on forward voltage measurements.
- (2) All measurements were made under the standardized environment of Seoul Semiconductor In order to ensure availability, single color rank will not be orderable.

Color Bin Structure

Table 4. Bin Code description, I_F=700mA, T_i=85 ℃ (CRI 80)

Part Number	Luminous Flux [lm]			Color Chromaticity	Typical For	Typical Forward Voltage [V _F] ^{[1]*}			
	Bin Code	Min.	Max.	Coordinate	Bin Code	Min.	Max.		
	V3	223	237	- _ Refer to page 15 -	G	2.75	3.00		
SZ8-Y19-W0-C8	W1	237	254			2.75	3.00		
320-119-00-00	W2	254	271		Н	2.00	3.25		
	W3	271	285		П	3.00	3.25		
	V3	223	237	Refer to page.	G	2.75	3.00		
SZ8-Y19-WN-C8	W1	237	254		G		3.00		
326-1 19-WIN-C6	W2	254	271	16~17		0.00	2.05		
	W3	271	285		Н	3.00	3.25		
	V1	195	208		G	0.75	2.00		
070)/40)	V2	208	223	Refer to page.	G	2.75	3.00		
SZ8-Y19-WW-C8	V3	223	237	18~20			2.05		
	W1	237	254	'	Н	3.00	3.25		

Table 5. Luminous Flux rank distribution (CRI 80)

Available Rank

сст	CIE	Luminous Flux Rank							
6,000 ~ 7,000K	Α	V1	V2	V3	W1	W2	W3		
5,300 – 6,000K	В	V1	V2	V3	W1	W2	W3		
4,700 ~ 5,300K	С	V1	V2	V3	W1	W2	W3		
4,200 ~ 4,700K	D	V1	V2	V3	W1	W2	W3		
3,700 ~ 4,200K	Е	V1	V2	V3	W1	W2	W3		
3,200 ~ 3,700K	F	V1	V2	V3	W1	W2	W3		
2,900 ~ 3,200K	G	V1	V2	V3	W1	W2	W3		
2,600 ~ 2,900K	Н	V1	V2	V3	W1	W2	W3		

Notes

- (1) Tolerance is ± 0.06 V on forward voltage measurements.
- (2) All measurements were made under the standardized environment of Seoul Semiconductor In order to ensure availability, single color rank will not be orderable.

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Color Bin Structure

Table 4. Bin Code description, I_F=700mA, T_i=85 ℃ (CRI 90)

Part Number	Lum	inous Flux	[lm]	Color Chromaticity	Typical For	Typical Forward Voltage [V _F] ^{[1]*}			
	Bin Code	Min.	Max.	Coordinate	Bin Code	Min.	Max.		
	V1	195	208		G	0.75	3.00		
SZ8-Y19-W0-C9	V2	208	223	Refer to page 15 -		2.75	3.00		
320-119-00-09	V3	223	237		Н	3.00	3.25		
	W1	237	254		П	3.00	3.25		
	V1	195	208	Refer to page.	G	2.75	3.00		
SZ8-Y19-WN-C9	V2	208	223		G		3.00		
326-119-WN-C9	V3	223	237	16~17		0.00	2.05		
	W1	237	254		Н	3.00	3.25		
	U2	172	182		G	0.75	2.00		
670 3/40 34/34 60	U3	182	195	Refer to page.	G	2.75	3.00		
SZ8-Y19-WW-C9	V1	195	208	18~20			2.05		
	V2	208	223	'	Н	3.00	3.25		

Table 5. Luminous Flux rank distribution (CRI 90)

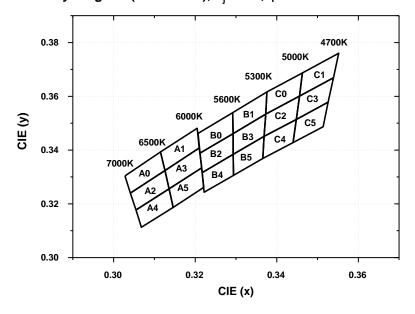
Available Rank

сст	CIE	Luminous Flux Rank							
6,000 ~ 7,000K	Α	U2	U3	V1	V2	V3	W1		
5,300 – 6,000K	В	U2	U3	V1	V2	V3	W1		
4,700 ~ 5,300K	С	U2	U3	V1	V2	V3	W1		
4,200 ~ 4,700K	D	U2	U3	V1	V2	V3	W1		
3,700 ~ 4,200K	Е	U2	U3	V1	V2	V3	W1		
3,200 ~ 3,700K	F	U2	U3	V1	V2	V3	W1		
2,900 ~ 3,200K	G	U2	U3	V1	V2	V3	W1		
2,600 ~ 2,900K	Н	U2	U3	V1	V2	V3	W1		

- (1) Tolerance is $\pm 0.06V$ on forward voltage measurements.
- (2) All measurements were made under the standardized environment of Seoul Semiconductor In order to ensure availability, single color rank will not be orderable.

Color Bin Structure

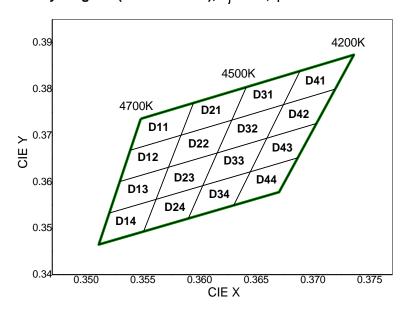
CIE Chromaticity Diagram (Cool white), T_j =85 $^{\circ}$ C, I_F =700mA



	40	А	.1	A:	2	А	3
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3028	0.3304	0.3115	0.3393	0.3041	0.3240	0.3126	0.3324
0.3041	0.3240	0.3126	0.3324	0.3055	0.3177	0.3136	0.3256
0.3126	0.3324	0.3210	0.3408	0.3136	0.3256	0.3216	0.3334
0.3115	0.3393	0.3205	0.3481	0.3126	0.3324	0.3210	0.3408
F	\ 4	A	.5	В	0	В	1
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3055	0.3177	0.3136	0.3256	0.3207	0.3462	0.3292	0.3539
0.3068	0.3113	0.3146	0.3187	0.3212	0.3389	0.3293	0.3461
0.3146	0.3187	0.3221	0.3261	0.3293	0.3461	0.3373	0.3534
0.3136	0.3256	0.3216	0.3334	0.3292	0.3539	0.3376	0.3616
E	32	В	3	В	4	В	5
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3212	0.3389	0.3293	0.3461	0.3217	0.3316	0.3293	0.3384
0.3217	0.3316	0.3293	0.3384	0.3222	0.3243	0.3294	0.3306
0.3293	0.3384	0.3369	0.3451	0.3294	0.3306	0.3366	0.3369
0.3293	0.3461	0.3373	0.3534	0.3293	0.3384	0.3369	0.3451
C	0	С (1	C.	2	С	3
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3376	0.3616	0.3463	0.3687	0.3373	0.3534	0.3456	0.3601
0.3373	0.3534	0.3456	0.3601	0.3369	0.3451	0.3448	0.3514
0.3456	0.3601	0.3539	0.3669	0.3448	0.3514	0.3526	0.3578
0.3463	0.3687	0.3552	0.3760	0.3456	0.3601	0.3539	0.3669
C	C4	C	5				
CIE x	CIE y	CIE x	CIE y				
0.3369	0.3451	0.3448	0.3514				
0.3366	0.3369	0.3440	0.3428				
0.3440	0.3428	0.3514	0.3487				
0.3448	0.3514	0.3526	0.3578				

Color Bin Structure

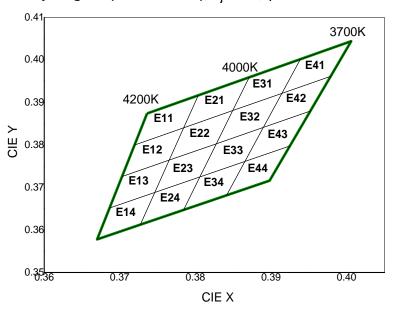
CIE Chromaticity Diagram (Neutral White), T_j =85 $^{\circ}$ C, I_F =700mA



D.	11	D	21	D3	31	D	41
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3548	0.3736	0.3595	0.3770	0.3641	0.3804	0.3689	0.3839
0.3539	0.3668	0.3584	0.3701	0.3628	0.3733	0.3674	0.3767
0.3584	0.3701	0.3628	0.3733	0.3674	0.3767	0.3720	0.3800
0.3595	0.3770	0.3641	0.3804	0.3689	0.3839	0.3736	0.3874
D.	12	D	22	D3	32	D ₁	42
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3539	0.3668	0.3584	0.3701	0.3628	0.3733	0.3674	0.3767
0.3530	0.3601	0.3573	0.3632	0.3616	0.3663	0.3659	0.3694
0.3573	0.3632	0.3616	0.3663	0.3659	0.3694	0.3703	0.3726
0.3584	0.3701	0.3628	0.3733	0.3674	0.3767	0.3720	0.3800
D.	13	D:	23	D3	33	D ₄	43
CIE x	CIE y	CIE x	23 CIE y	CIE x	CIE y	CIE x	43 CIE y
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
CIE x 0.3530	CIE y 0.3601	CIE x 0.3573	CIE y 0.3632	CIE x 0.3616	CIE y 0.3663	CIE x 0.3659	CIE y 0.3694
CIE x 0.3530 0.3520	CIE y 0.3601 0.3533	CIE x 0.3573 0.3562	CIE y 0.3632 0.3562	CIE x 0.3616 0.3603	CIE y 0.3663 0.3592	CIE x 0.3659 0.3645	CIE y 0.3694 0.3622
CIE x 0.3530 0.3520 0.3562 0.3573	CIE y 0.3601 0.3533 0.3562	CIE x 0.3573 0.3562 0.3603 0.3616	CIE y 0.3632 0.3562 0.3592	CIE x 0.3616 0.3603 0.3645	CIE y 0.3663 0.3592 0.3622 0.3694	CIE x 0.3659 0.3645 0.3687 0.3703	CIE y 0.3694 0.3622 0.3652
CIE x 0.3530 0.3520 0.3562 0.3573	CIE y 0.3601 0.3533 0.3562 0.3632	CIE x 0.3573 0.3562 0.3603 0.3616	CIE y 0.3632 0.3562 0.3592 0.3663	CIE x 0.3616 0.3603 0.3645 0.3659	CIE y 0.3663 0.3592 0.3622 0.3694	CIE x 0.3659 0.3645 0.3687 0.3703	CIE y 0.3694 0.3622 0.3652 0.3726
CIE x 0.3530 0.3520 0.3562 0.3573	CIE y 0.3601 0.3533 0.3562 0.3632	CIE x 0.3573 0.3562 0.3603 0.3616	CIE y 0.3632 0.3562 0.3592 0.3663	CIE x 0.3616 0.3603 0.3645 0.3659	CIE y 0.3663 0.3592 0.3622 0.3694	CIE x 0.3659 0.3645 0.3687 0.3703	CIE y 0.3694 0.3622 0.3652 0.3726
0.3530 0.3520 0.3562 0.3573	CIE y 0.3601 0.3533 0.3562 0.3632 14 CIE y	CIE x 0.3573 0.3562 0.3603 0.3616 D) CIE x	CIE y 0.3632 0.3562 0.3592 0.3663 24 CIE y	CIE x 0.3616 0.3603 0.3645 0.3659 D3 CIE x	CIE y 0.3663 0.3592 0.3622 0.3694 34 CIE y	CIE x 0.3659 0.3645 0.3687 0.3703 D.CIE x	CIE y 0.3694 0.3622 0.3652 0.3726 44 CIE y
CIE x 0.3530 0.3520 0.3562 0.3573 CIE x 0.3520	CIE y 0.3601 0.3533 0.3562 0.3632 14 CIE y 0.3533	CIE x 0.3573 0.3562 0.3603 0.3616 D: CIE x 0.3562	CIE y 0.3632 0.3562 0.3592 0.3663 24 CIE y 0.3562	CIE x 0.3616 0.3603 0.3645 0.3659 D3 CIE x 0.3603	CIE y 0.3663 0.3592 0.3622 0.3694 34 CIE y 0.3592	CIE x 0.3659 0.3645 0.3687 0.3703 December 2	CIE y 0.3694 0.3622 0.3652 0.3726 44 CIE y 0.3622

Color Bin Structure

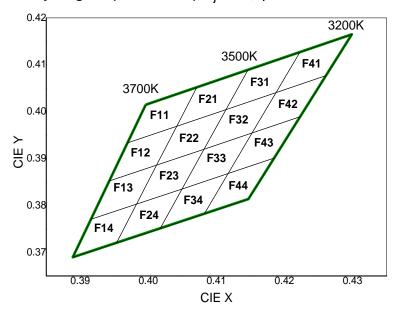
CIE Chromaticity Diagram (Neutral White), T_j =85 $^{\circ}$ C, I_F =700mA



E ^r	11	E	21	E3	31	E	41
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3736	0.3874	0.3804	0.3917	0.3871	0.3959	0.3939	0.4002
0.3720	0.3800	0.3784	0.3841	0.3849	0.3881	0.3914	0.3922
0.3784	0.3841	0.3849	0.3881	0.3914	0.3922	0.3979	0.3962
0.3804	0.3917	0.3871	0.3959	0.3939	0.4002	0.4006	0.4044
E ²	12	E	22	E3	32	E.	42
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3720	0.3800	0.3784	0.3841	0.3849	0.3881	0.3914	0.3922
0.3703	0.3726	0.3765	0.3765	0.3828	0.3803	0.3890	0.3842
0.3765	0.3765	0.3828	0.3803	0.3890	0.3842	0.3952	0.3880
0.3784	0.3841	0.3849	0.3881	0.3914	0.3922	0.3979	0.3962
E.	13	E	23	E3	33	E.	43
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3703	0.3726	0.3765	0.3765	0.3828	0.3803	0.3890	0.3842
0.3687	0.3652	0.3746	0.3689	0.3806	0.3725	0.3865	0.3762
0.3746	0.3689	0.3806	0.3725	0.3865	0.3762	0.3925	0.3798
0.3765	0.3765	0.3828	0.3803	0.3890	0.3842	0.3952	0.3880
E.	14	E	24	E3	34	E.	44
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3687	0.3652	0.3746	0.3689	0.3806	0.3725	0.3865	0.3762
0.3670	0.3578	0.3727	0.3613	0.3784	0.3647	0.3841	0.3682
0.3727	0.3613	0.3784	0.3647	0.3841	0.3682	0.3898	0.3716
0.0121	0.0010	0.0704	0.00+1	0.3041	0.0002	0.0000	

Color Bin Structure

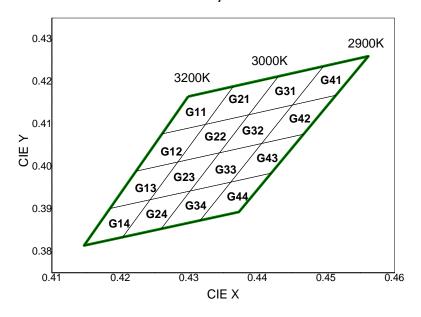
CIE Chromaticity Diagram (Warm White), T_j =85 $^{\circ}$ C, I_F =700mA



F1	l1	F:	21	F3	31	F4	41
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3996	0.4015	0.4071	0.4052	0.4146	0.4089	0.4223	0.4127
0.3969	0.3934	0.4042	0.3969	0.4114	0.4005	0.4187	0.4041
0.4042	0.3969	0.4114	0.4005	0.4187	0.4041	0.4261	0.4077
0.4071	0.4052	0.4146	0.4089	0.4223	0.4127	0.4299	0.4165
F1	12	F:	22	F3	32	F4	42
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3969	0.3934	0.4042	0.3969	0.4114	0.4005	0.4187	0.4041
0.3943	0.3853	0.4012	0.3886	0.4082	0.3920	0.4152	0.3955
0.4012	0.3886	0.4082	0.3920	0.4152	0.3955	0.4223	0.3990
0.4042	0.3969	0.4114	0.4005	0.4187	0.4041	0.4261	0.4077
F1	13	F:	23	F3	33	F4	43
•							
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
							CIE y 0.3955
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	
CIE x 0.3943	CIE y 0.3853	CIE x 0.4012	CIE y 0.3886	CIE x 0.4082	CIE y 0.3920	CIE x 0.4152	0.3955
CIE x 0.3943 0.3916	CIE y 0.3853 0.3771	CIE x 0.4012 0.3983	CIE y 0.3886 0.3803	CIE x 0.4082 0.4049	CIE y 0.3920 0.3836	CIE x 0.4152 0.4117	0.3955
CIE x 0.3943 0.3916 0.3983	CIE y 0.3853 0.3771 0.3803 0.3886	CIE x 0.4012 0.3983 0.4049 0.4082	CIE y 0.3886 0.3803 0.3836	CIE x 0.4082 0.4049 0.4117	CIE y 0.3920 0.3836 0.3869 0.3955	CIE x 0.4152 0.4117 0.4185 0.4223	0.3955 0.3869 0.3902
CIE x 0.3943 0.3916 0.3983 0.4012	CIE y 0.3853 0.3771 0.3803 0.3886	CIE x 0.4012 0.3983 0.4049 0.4082	CIE y 0.3886 0.3803 0.3836 0.3920	CIE x 0.4082 0.4049 0.4117 0.4152	CIE y 0.3920 0.3836 0.3869 0.3955	CIE x 0.4152 0.4117 0.4185 0.4223	0.3955 0.3869 0.3902 0.3990
CIE x 0.3943 0.3916 0.3983 0.4012	CIE y 0.3853 0.3771 0.3803 0.3886	CIE x 0.4012 0.3983 0.4049 0.4082	CIE y 0.3886 0.3803 0.3836 0.3920	CIE x 0.4082 0.4049 0.4117 0.4152	CIE y 0.3920 0.3836 0.3869 0.3955	CIE x 0.4152 0.4117 0.4185 0.4223	0.3955 0.3869 0.3902 0.3990
CIE x 0.3943 0.3916 0.3983 0.4012 F ² CIE x	CIE y 0.3853 0.3771 0.3803 0.3886 14 CIE y	CIE x 0.4012 0.3983 0.4049 0.4082	CIE y 0.3886 0.3803 0.3836 0.3920 24 CIE y	CIE x 0.4082 0.4049 0.4117 0.4152 FX CIE x	CIE y 0.3920 0.3836 0.3869 0.3955 34 CIE y	CIE x 0.4152 0.4117 0.4185 0.4223 CIE x	0.3955 0.3869 0.3902 0.3990 44 CIE y
CIE x 0.3943 0.3916 0.3983 0.4012 F7 CIE x 0.3916	CIE y 0.3853 0.3771 0.3803 0.3886 14 CIE y 0.3771	CIE x 0.4012 0.3983 0.4049 0.4082 CIE x 0.3983	CIE y 0.3886 0.3803 0.3836 0.3920 24 CIE y 0.3803	CIE x 0.4082 0.4049 0.4117 0.4152 CIE x 0.4049	CIE y 0.3920 0.3836 0.3869 0.3955 34 CIE y 0.3836	CIE x 0.4152 0.4117 0.4185 0.4223 F2 CIE x 0.4117	0.3955 0.3869 0.3902 0.3990 44 CIE y 0.3869

Color Bin Structure

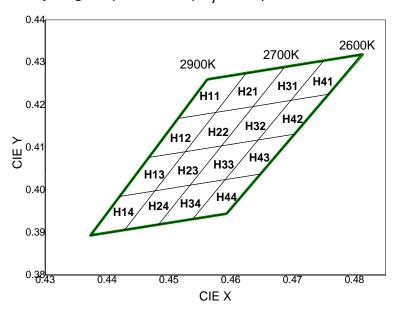
CIE Chromaticity Diagram (Warm White), T_j =85 $^{\circ}$ C, I_F =700mA



G.	11	G	21	G	31	G	41
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.4299	0.4165	0.4364	0.4188	0.4430	0.4212	0.4496	0.4236
0.4261	0.4077	0.4324	0.4099	0.4387	0.4122	0.4451	0.4145
0.4324	0.4100	0.4387	0.4122	0.4451	0.4145	0.4514	0.4168
0.4365	0.4189	0.4430	0.4212	0.4496	0.4236	0.4562	0.4260
G.	12	G	22	G	32	G.	42
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.4261	0.4077	0.4324	0.4100	0.4387	0.4122	0.4451	0.4145
0.4223	0.3990	0.4284	0.4011	0.4345	0.4033	0.4406	0.4055
0.4284	0.4011	0.4345	0.4033	0.4406	0.4055	0.4468	0.4077
0.4324	0.4100	0.4387	0.4122	0.4451	0.4145	0.4515	0.4168
G.	12	c	23	G	2	G	43
	19	G.	20	G.	ာ	<u> </u>	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
CIE x 0.4223	CIE y 0.3990	CIE x 0.4284	CIE y 0.4011	CIE x 0.4345	CIE y 0.4033	CIE x 0.4406	CIE y 0.4055
CIE x 0.4223 0.4185	CIE y 0.3990 0.3902	CIE x 0.4284 0.4243	CIE y 0.4011 0.3922	CIE x 0.4345 0.4302	CIE y 0.4033 0.3943	CIE x 0.4406 0.4361	CIE y 0.4055 0.3964
CIE x 0.4223 0.4185 0.4243	CIE y 0.3990 0.3902 0.3922 0.4011	CIE x 0.4284 0.4243 0.4302 0.4345	CIE y 0.4011 0.3922 0.3943	CIE x 0.4345 0.4302 0.4361	CIE y 0.4033 0.3943 0.3964 0.4055	CIE x 0.4406 0.4361 0.4420 0.4468	CIE y 0.4055 0.3964 0.3985
CIE x 0.4223 0.4185 0.4243 0.4284	CIE y 0.3990 0.3902 0.3922 0.4011	CIE x 0.4284 0.4243 0.4302 0.4345	CIE y 0.4011 0.3922 0.3943 0.4033	CIE x 0.4345 0.4302 0.4361 0.4406	CIE y 0.4033 0.3943 0.3964 0.4055	CIE x 0.4406 0.4361 0.4420 0.4468	CIE y 0.4055 0.3964 0.3985 0.4077
CIE x 0.4223 0.4185 0.4243 0.4284 G	CIE y 0.3990 0.3902 0.3922 0.4011	CIE x 0.4284 0.4243 0.4302 0.4345	CIE y 0.4011 0.3922 0.3943 0.4033	CIE x 0.4345 0.4302 0.4361 0.4406	CIE y 0.4033 0.3943 0.3964 0.4055	CIE x 0.4406 0.4361 0.4420 0.4468	CIE y 0.4055 0.3964 0.3985 0.4077
CIE x 0.4223 0.4185 0.4243 0.4284 G: CIE x	CIE y 0.3990 0.3902 0.3922 0.4011 14 CIE y	CIE x 0.4284 0.4243 0.4302 0.4345 G CIE x	CIE y 0.4011 0.3922 0.3943 0.4033 24 CIE y	CIE x 0.4345 0.4302 0.4361 0.4406	CIE y 0.4033 0.3943 0.3964 0.4055 34 CIE y	CIE x 0.4406 0.4361 0.4420 0.4468 GCIE x	CIE y 0.4055 0.3964 0.3985 0.4077 44 CIE y
CIE x 0.4223 0.4185 0.4243 0.4284 G: CIE x 0.4243	CIE y 0.3990 0.3902 0.3922 0.4011 14 CIE y 0.3922	CIE x 0.4284 0.4243 0.4302 0.4345 G CIE x 0.4302	CIE y 0.4011 0.3922 0.3943 0.4033 24 CIE y 0.3943	CIE x 0.4345 0.4302 0.4361 0.4406 GG CIE x 0.4302	CIE y 0.4033 0.3943 0.3964 0.4055 34 CIE y 0.3943	CIE x 0.4406 0.4361 0.4420 0.4468 GCIE x 0.4361	CIE y 0.4055 0.3964 0.3985 0.4077 44 CIE y 0.3964

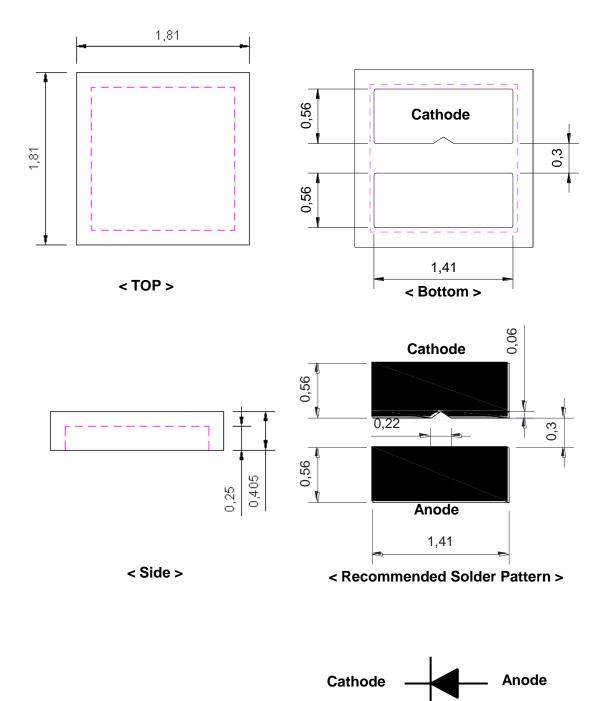
Color Bin Structure

CIE Chromaticity Diagram (Warm White), T_j =85 $^{\circ}$ C, I_F =700mA



H1	11	H	21	H	31 <u> </u>	H	41
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.4562	0.4260	0.4625	0.4275	0.4687	0.4289	0.4750	0.4304
0.4515	0.4168	0.4575	0.4182	0.4636	0.4197	0.4697	0.4211
0.4575	0.4182	0.4636	0.4197	0.4697	0.4211	0.4758	0.4225
0.4625	0.4275	0.4687	0.4289	0.4750	0.4304	0.4810	0.4319
H1	12	H	22	На	32	H ₄	42
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.4515	0.4168	0.4575	0.4182	0.4636	0.4197	0.4697	0.4211
0.4468	0.4077	0.4526	0.4090	0.4585	0.4104	0.4644	0.4118
0.4526	0.4090	0.4585	0.4104	0.4644	0.4118	0.4703	0.4132
0.4575	0.4182	0.4636	0.4197	0.4697	0.4211	0.4758	0.4225
H1	13	H	23	нз	33	H	43
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
CIE x 0.4468	CIE y 0.4077	CIE x 0.4526	CIE y 0.4090	CIE x 0.4585	CIE y 0.4104	CIE x 0.4644	CIE y 0.4118
							<u> </u>
0.4468	0.4077	0.4526	0.4090	0.4585	0.4104	0.4644	0.4118
0.4468 0.4420	0.4077	0.4526 0.4477	0.4090	0.4585 0.4534	0.4104	0.4644 0.4591	0.4118 0.4025
0.4468 0.4420 0.4477	0.4077 0.3985 0.3998 0.4090	0.4526 0.4477 0.4534 0.4585	0.4090 0.3998 0.4012	0.4585 0.4534 0.4591	0.4104 0.4012 0.4025 0.4118	0.4644 0.4591 0.4648	0.4118 0.4025 0.4038 0.4132
0.4468 0.4420 0.4477 0.4526	0.4077 0.3985 0.3998 0.4090	0.4526 0.4477 0.4534 0.4585	0.4090 0.3998 0.4012 0.4104	0.4585 0.4534 0.4591 0.4644	0.4104 0.4012 0.4025 0.4118	0.4644 0.4591 0.4648 0.4703	0.4118 0.4025 0.4038 0.4132
0.4468 0.4420 0.4477 0.4526	0.4077 0.3985 0.3998 0.4090	0.4526 0.4477 0.4534 0.4585	0.4090 0.3998 0.4012 0.4104	0.4585 0.4534 0.4591 0.4644	0.4104 0.4012 0.4025 0.4118	0.4644 0.4591 0.4648 0.4703	0.4118 0.4025 0.4038 0.4132
0.4468 0.4420 0.4477 0.4526 H1	0.4077 0.3985 0.3998 0.4090	0.4526 0.4477 0.4534 0.4585 H: CIE x	0.4090 0.3998 0.4012 0.4104 CIE y	0.4585 0.4534 0.4591 0.4644 H3	0.4104 0.4012 0.4025 0.4118 34 CIE y	0.4644 0.4591 0.4648 0.4703 H4	0.4118 0.4025 0.4038 0.4132 44 CIE y
0.4468 0.4420 0.4477 0.4526 H' CIE x 0.4420	0.4077 0.3985 0.3998 0.4090 14 CIE y 0.3985	0.4526 0.4477 0.4534 0.4585 H: CIE x 0.4477	0.4090 0.3998 0.4012 0.4104 24 CIE y 0.3998	0.4585 0.4534 0.4591 0.4644 H3 CIE x 0.4534	0.4104 0.4012 0.4025 0.4118 34 CIE y 0.4012	0.4644 0.4591 0.4648 0.4703 H ² CIE x 0.4591	0.4118 0.4025 0.4038 0.4132 44 CIE y 0.4025

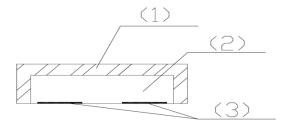
Mechanical Dimensions



- (1) All dimensions are in millimeters.
- (2) Scale: none
- (3) Undefined tolerance is ± 0.2 mm

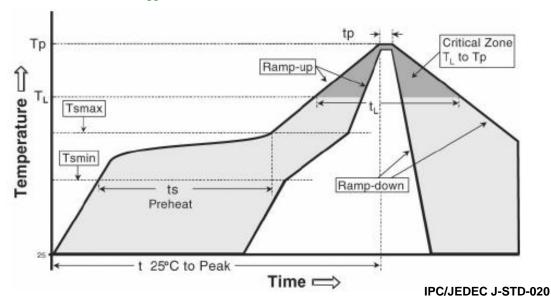
< Inner circuit >

Material Structure



No.	List	Material
1	Encapsulation	Silicone, Phosphor
2	Chip Source	GaN ON SAPPHIRE
3	Solder-PAD	Metal (Au)

Reflow Soldering Characteristics



Profile Feature	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3° C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	150 °C 180 °C 80-120 seconds
Time maintained above: - Temperature (TL) - Time (tL)	217~220°C 80-100 seconds
Peak Temperature (Tp)	250~255℃
Time within 5°C of actual Peak Temperature (tp)2	20-40 seconds
Ramp-down Rate	6 °C/second max.
Time 25°C to Peak Temperature	8 minutes max.
Atmosphere	Nitrogen (O2<1000ppm)

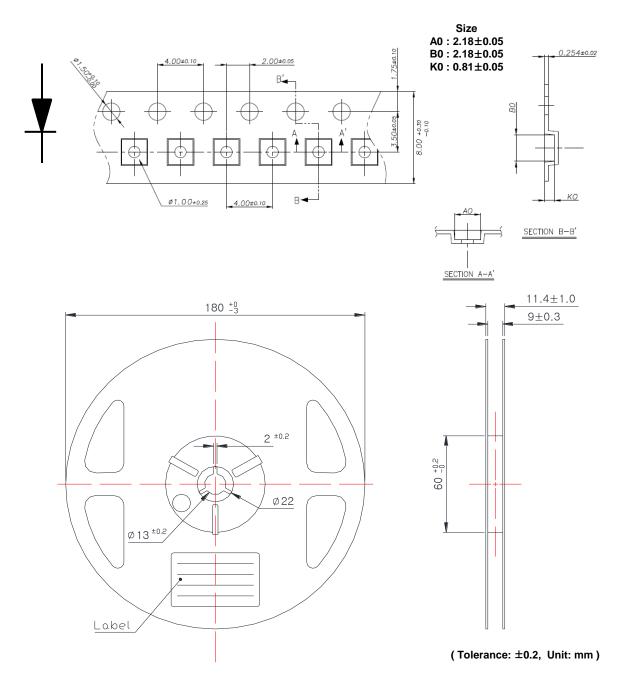
Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair..
- (3) Do not put stress on the LEDs during heating.
- (4) After reflow, do not clean PCB by water or solvent.

SMT recommendation

- (1) After reflow, Over 80% reflectance of PSR is recommended. → Tamura RPW-8000-xx
- (2) Solder paste materials (SAC 305, No Cleaning Paste) → Senju M705-GRN360-KV
- (3) We recommend TOV Test 1.8v~2.8v at 1uA (per LED)
- (4) We recommend IR Test 0~1uA at -5V (per LED)

Emitter Tape & Reel Packaging



Notes:

(1) Quantity: 1,500pcs/Reel (empty slot possible in taping reel)

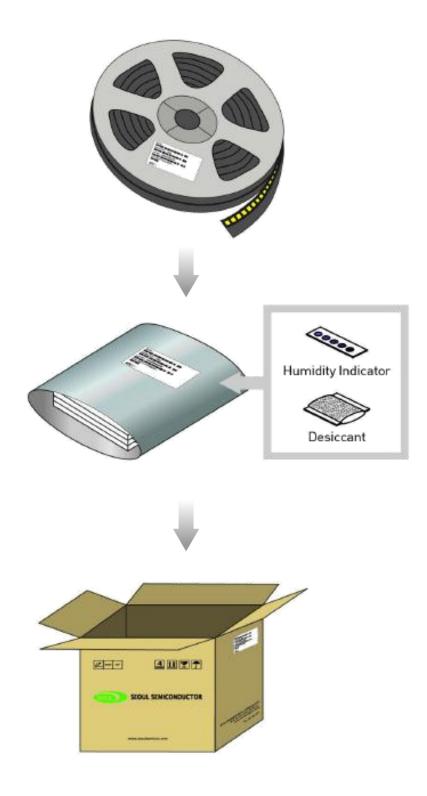
(2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ± 0.2 mm

(3) Adhesion Strength of Cover Tape : Adhesion strength to be 0.1-0.7N when the cover

tape is turned off from the carrier tape at the angle of 10° to the carrier tape

(4) Package: P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package

Packaging Information



Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



- (2) Do not use tweezers to pick up or handle WICOP2 LEDs. A vacuum pick up should only be used.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is smaller than the LED's area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing.
- (5) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (6) Avoid leaving fingerprints on silicone resin parts.

Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend storing LEDs in a dry box with a desiccant. The recommended storage temperature range is 5° C to 30° C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMD techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 30 °C Humidity : less than RH60%
- b. If the package has been opened more than 1 year (MSL 2) or the color of the desiccant changes, components should be dried for 10-24hr at 65 ± 5 °C
- (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- (4) Do not rapidly cool device after soldering.
- (5) Components should not be mounted on warped (non coplanar) portion of PCB.
- (6) Radioactive exposure is not considered for the products listed here in.
- (7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc.
- (9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
- (10) The appearance and specifications of the product may be modified for improvement without notice.
- (11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

Precaution for Use

- (12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (13) The slug is electrically isolated.
- (14) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (15) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the rev erse voltage is applied to LED, migration can be generated resulting in LED damage.
- (16) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.
- a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
 (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.
- c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:
 - A surge protection circuit
 - An appropriately rated over voltage protection device
 - A current limiting device



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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